Dual Non-Inverting Schmitt Trigger Buffer

The NL27WZ17 is a high performance dual buffer operating from a 1.65 to 5.5 V supply. At $V_{\rm CC}$ = 3.0 V, high impedance TTL compatible inputs significantly reduce current loading to input drivers while the TTL compatible outputs offer improved switching noise performance.

Features

- Extremely High Speed: t_{PD} 2.0 ns (typical) at $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Overvoltage Tolerant Inputs
- LVTTL Compatible Interface Capability with 5.0 V TTL Logic with V_{CC} = 3.0 V (2.7–3.3)
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability at $V_{CC} = 3.0 \text{ V}$
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72; Equivalent Gate = 18
- Pb-Free Package is Available

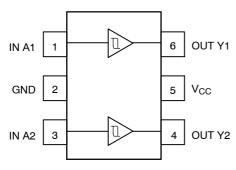


Figure 1. Pinout (Top View)

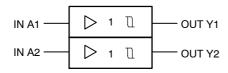


Figure 2. Logic Symbol

PIN ASSIGNMENT

1	IN A1			
2	GND			
3	IN A2			
4	OUT Y2			
5	V _{CC}			
6	OUT Y1			

FUNCTION TABLE

▼ Output
L
Н



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SC-88/SOT-363/SC-70 DF SUFFIX CASE 419B

MARKING DIAGRAM



MX = Specific Device Code

I = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NL27WZ17DFT2	SC-88	3000/Tape & Reel
NL27WZ17DFT2G	SC-88 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Characteris	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \le V_{I} \le +7.0$	V
Vo	DC Output Voltage Out	$-0.5 \le V_{O} \le 7.0$	V	
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND	-50	mA
Io	DC Output Sink Current		±50	mA
Icc	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
P _D	Power Dissipation in Still Air		200	mW
$\theta_{\sf JA}$	Thermal Resistance		333	°C/W
TL	Lead Temperature, 1 mm from case for 10 s		260	°C
TJ	Junction Temperature under Bias		+ 150	°C
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 150 N/A	V
I _{Latch-} Up	Latch-Up Performance Above V _{CC} ar	nd Below GND at 85°C (Note 5)	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- I_O absolute maximum rating must be observed.
 Tested to EIA/JESD22-A114-A
 Tested to EIA/JESD22-A115-A

- 4. Tested to JESD22-C101-A
- 5. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

Symbol	Para	Min	Max	Unit	
V _{CC}	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	٧
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	(High or LOW State)	0	5.5	V
T _A	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	V_{CC} = 2.5 V ±0.2 V V_{CC} = 3.0 V ±0.3 V V_{CC} = 5.0 V ±0.5 V	0 0 0	No Limit No Limit No Limit	ns/V

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	T _A	= 25°C		-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _T +	Positive Input Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.6 1.0 1.2 1.3 1.9 2.2	1.0 1.5 1.7 1.9 2.7 3.3	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	\ \
V _T -	Negative Input Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.2 0.4 0.5 0.6 1.0	0.5 0.75 0.87 1.0 1.5 1.9	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0	0.8 1.15 1.4 1.5 2.0 2.3	V
V _H	Input Hysteresis Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.1 0.25 0.3 0.4 0.6 0.7	0.48 0.75 0.83 0.93 1.2 1.4	0.9 1.1 1.15 1.2 1.5 1.7	0.1 0.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5	V
V _{OH}	High-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$\begin{split} I_{OH} &= -100 \ \mu A \\ I_{OH} &= -3.0 \ mA \\ I_{OH} &= -8.0 \ mA \\ I_{OH} &= -12 \ mA \\ I_{OH} &= -16 \ mA \\ I_{OH} &= -24 \ mA \\ I_{OH} &= -32 \ mA \end{split}$	1.65-5.5 1.65 2.3 2.7 3.0 3.0 4.5	V _{CC} -0.1 1.29 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.52 2.1 2.4 2.7 2.5 4.0		V _{CC} -0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$\begin{split} I_{OL} &= 100 \; \mu\text{A} \\ I_{OL} &= 4.0 \; \text{mA} \\ I_{OL} &= 8.0 \; \text{mA} \\ I_{OL} &= 12 \; \text{mA} \\ I_{OL} &= 16 \; \text{mA} \\ I_{OL} &= 24 \; \text{mA} \\ I_{OL} &= 32 \; \text{mA} \end{split}$	1.65-5.5 1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	0 to 5.5			±0.1	_	±1.0	μΑ
I _{OFF}	Power Off-Output Leakage Current	V _{OUT} = 5.5 V	0			1.0		10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5			1.0		10	μА

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

			V _{cc}	T _A = 25°C		-55°C ≤ 1			
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} t _{PHL}	Propagation Delay Input A to Y	R_L = 1.0 M Ω , C_L = 15 pF	1.65 1.8 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5	2.0 2.0 1.0 1.0 0.5	9.1 7.6 5.0 3.7 3.1	15 12.5 9.0 6.3 5.2	2.0 2.0 1.0 1.0 0.5	15.6 13 9.5 6.5 5.5	ns
		$R_L = 500 \Omega, C_L = 50 pF$	3.3 ± 0.3 5.0 ± 0.5	1.5 0.8	4.4 3.7	7.2 5.9	1.5 0.8	7.5 6.2	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V},$ $V_I = 0 \text{ V or } V_{CC}$	7.0	pF
C _{PD}	Power Dissipation Capacitance	$ \begin{array}{l} 10 \text{ MHz, V}_{CC} = 3.3 \text{ V, V}_{I} = 0 \text{ V} \\ \text{or V}_{CC} \ 10 \text{ MHz, V}_{CC} = 5.5 \text{ V,} \\ \text{V}_{I} = 0 \text{ V or V}_{CC} \end{array} $	9.0 11	pF

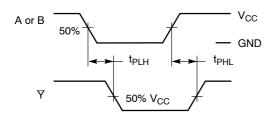
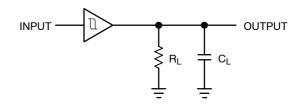


Figure 3. Switching Waveforms



A 1–MHz square input wave is recommended for propagation delay tests.

Figure 4. Test Circuit

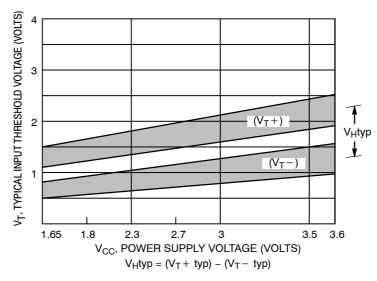


Figure 5. Typical Input Threshold, $V_{T}+$, $V_{T}-$ versus Power Supply Voltage

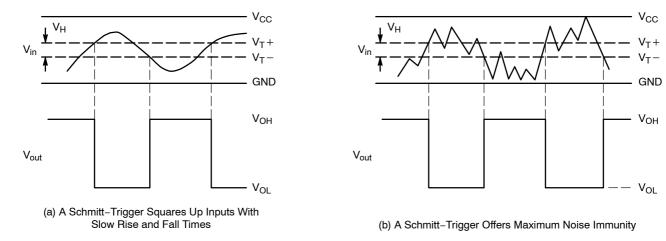
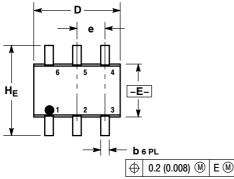


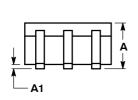
Figure 6. Typical Schmitt-Trigger Applications

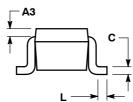
PACKAGE DIMENSIONS

SC-88/SOT-363/SC70-6 **DF SUFFIX**

CASE 419B-02 **ISSUE W**





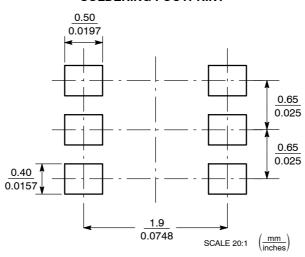


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MILLIMETERS				INCHES	3			
DIM	MIN	NOM	MAX	MIN	NOM	MAX			
Α	0.80	0.95	1.10	0.031	0.037	0.043			
A1	0.00	0.05	0.10	0.000	0.002	0.004			
А3		0.20 RE	F	(0.008 RE	EF			
b	0.10	0.21	0.30	0.004	0.008	0.012			
С	0.10	0.14	0.25	0.004	0.005	0.010			
D	1.80	2.00	2.20	0.070	0.078	0.086			
Е	1.15	1.25	1.35	0.045	0.049	0.053			
е	(0.65 BSC			0.026 BSC				
L	0.10	0.20	0.30	0.004	0.008	0.012			
HE	2.00	2.10	2.20	0.078	0.082	0.086			

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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